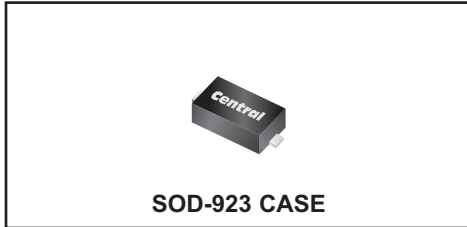


CMASH-4
SURFACE MOUNT SILICON
SCHOTTKY DIODE



DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMASH-4 is a high quality Schottky diode designed for applications where very small size and operational efficiency are prime requirements.

MARKING CODE: A

APPLICATIONS:

- DC-DC converters
- Voltage clamping
- Protection circuits
- Battery powered applications including cell phones, digital cameras, pagers, PDAs, laptop computers, etc.

FEATURES:

- Current ($I_O=200\text{mA}$)
- Low forward voltage drop ($V_F=0.35\text{V TYP @ } 1.0\text{mA}$)
- Low reverse current ($25\text{nA TYP @ } 30\text{V}$)
- Extremely fast switching (5.0ns MAX)
- Miniature, $0.8 \times 0.6 \times 0.4\text{mm}$, ultra low height profile surface mount package.

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Peak Repetitive Reverse Voltage
Average Forward Current
Peak Forward Surge Current, $t_p=8.3\text{ms}$
Power Dissipation
Operating Junction Temperature
Storage Temperature
Thermal Resistance

SYMBOL

SYMBOL		UNITS
V_{RRM}	40	V
I_O	200	mA
I_{FSM}	600	mA
P_D	100	mW
T_J	-65 to +125	$^\circ\text{C}$
T_{stg}	-65 to +150	$^\circ\text{C}$
Θ_{JA}	1000	$^\circ\text{C/W}$

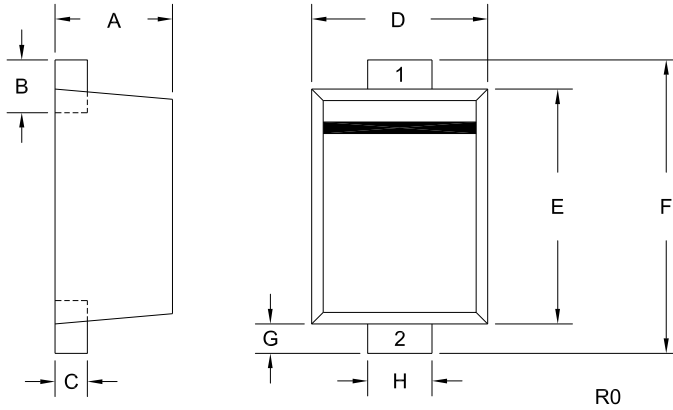
ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_R	$V_R=30\text{V}$		25	200	nA
BV_R	$I_R=10\mu\text{A}$	40			V
V_F	$I_F=1.0\text{mA}$		0.35	0.38	V
V_F	$I_F=15\text{mA}$		0.55	0.65	V
V_F	$I_F=40\text{mA}$		0.77	1.00	V
C_J	$V_R=0, f=1.0\text{MHz}$			5.0	pF
t_{rr}	$I_F=I_R=10\text{mA}, I_{rr}=1.0\text{mA}, R_L=100\Omega$			5.0	ns

CMASH-4
SURFACE MOUNT SILICON
SCHOTTKY DIODE



SOD-923 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Cathode
- 2) Anode

MARKING CODE: A

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.015	0.016	0.39	0.41
B	0.004	0.010	0.10	0.26
C	0.003	0.006	0.08	0.14
D	0.022	0.026	0.55	0.65
E	0.030	0.033	0.75	0.85
F	0.035	0.043	0.90	1.10
G	0.002	0.006	0.05	0.15
H	0.007	0.011	0.17	0.27

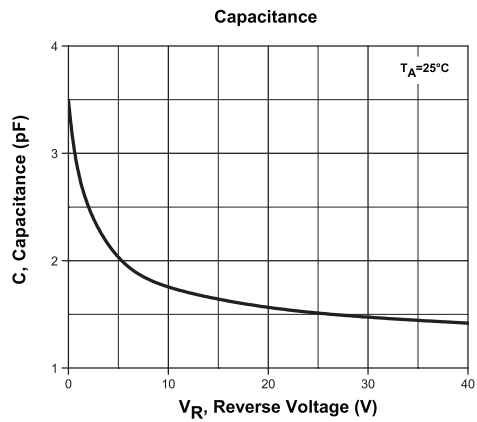
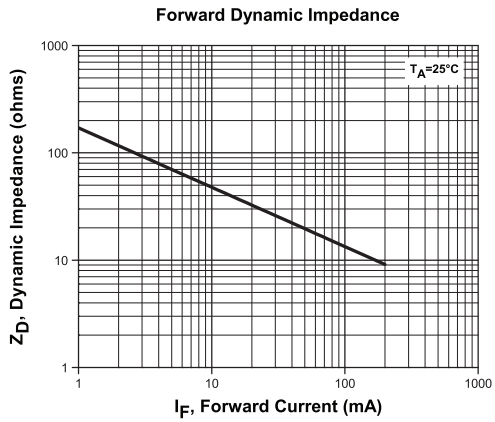
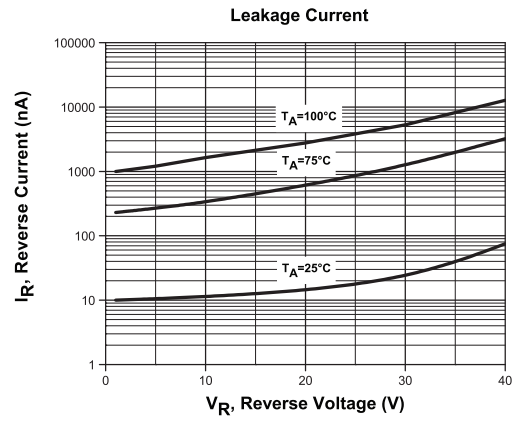
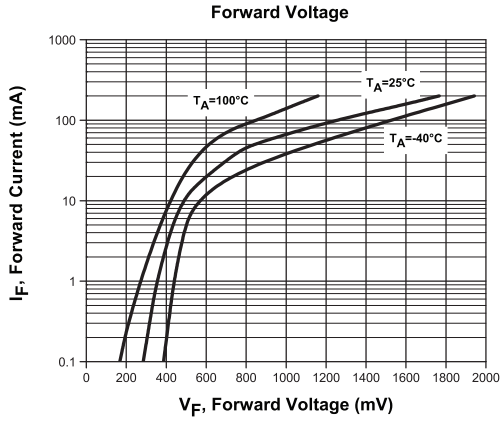
SOD-923 (REV: R0)

R2 (3-August 2015)

CMASH-4
SURFACE MOUNT SILICON
SCHOTTKY DIODE



TYPICAL ELECTRICAL CHARACTERISTICS

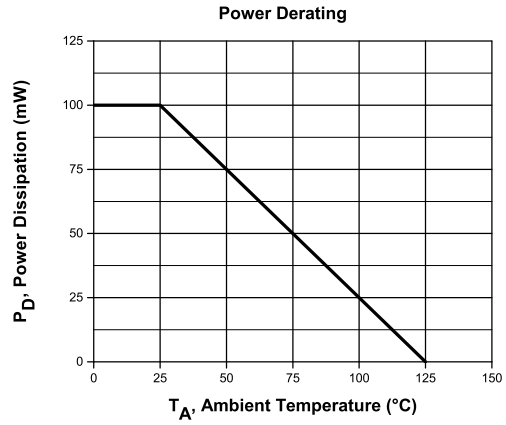
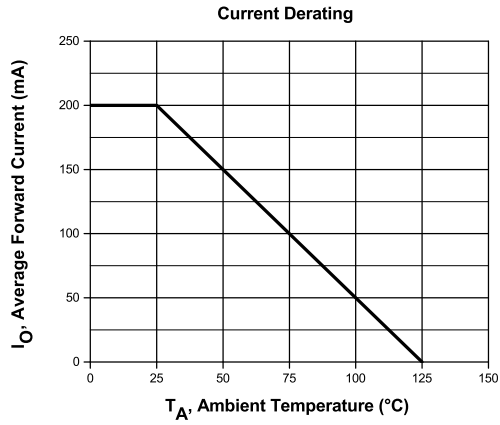


R2 (3-August 2015)

CMASH-4
SURFACE MOUNT SILICON
SCHOTTKY DIODE



TYPICAL ELECTRICAL CHARACTERISTICS



R2 (3-August 2015)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp.
145 Adams Avenue
Hauppauge, NY 11788 USA
Main Tel: (631) 435-1110
Main Fax: (631) 435-1824
Support Team Fax: (631) 435-3388
www.centrasemi.com

Worldwide Field Representatives:
www.centrasemi.com/wwreps

Worldwide Distributors:
www.centrasemi.com/wwdistributors

For the latest version of Central Semiconductor's **LIMITATIONS AND DAMAGES DISCLAIMER**, which is part of Central's Standard Terms and Conditions of sale, visit: www.centrasemi.com/terms